

**Product data sheet** 

## 1. General description

PNP low  $V_{CEsat}$  transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability: I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- Higher efficiency leading to less heat genereation
- High temperature applications up to 175 °C

## 3. Applications

- Power management
- DC-to-DC conversion
- Supply line switches
- · Battery charger switches
- · Peripheral drivers
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-	-50	V
I <sub>C</sub>	collector current			-	-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	-3	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -2 A; $I_B$ = -200 mA; $T_{amb}$ = 25 °C	[1]	-	-	150	mΩ

[1] Pulse test:  $t_p \le 300 \mu s$ ;  $\delta \le 0.02$ 



50 V, 2 A PNP low VCEsat transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	_
2	E	emitter		C
3	С	collector		В
				E sym132
			SOT23	3yi1132

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
PBSS5250TH	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5250TH	FH%

[1] % = placeholder for manufacturing site code

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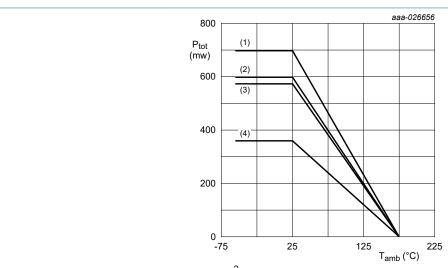
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-7	V
I <sub>C</sub>	collector current			-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-3	Α
I <sub>B</sub>	base current			-	-300	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	360	mW
			[2]	-	575	mW
			[3]	-	600	mW
			[4]	-	700	mW
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper, 1 cm<sup>2</sup>
- (2) FR4 PCB, 4-layer copper, standard footprint
- (3) FR4 PCB, single sided copper, 1 cm<sup>2</sup>
- (4) FR4 PCB, single sided copper, standard footprint

Fig. 1. Power derating curves for SOT23

#### 50 V, 2 A PNP low VCEsat transistor

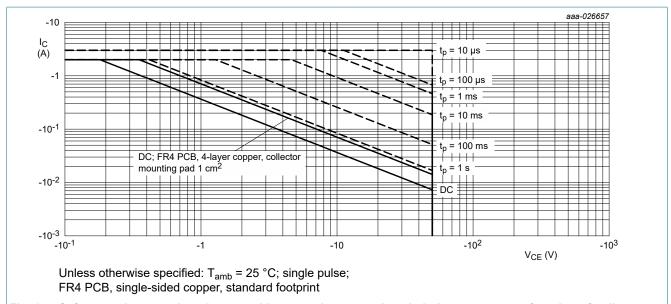


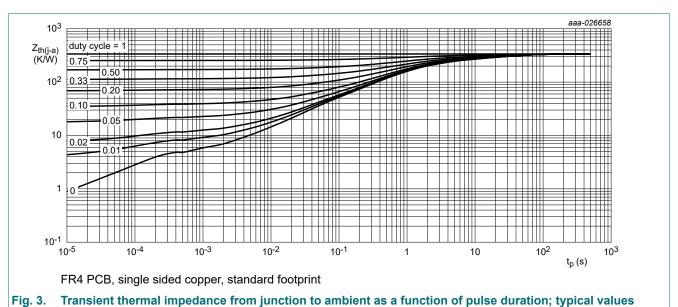
Fig. 2. Safe operating area; junction to ambient; continuous and peak drain currents as a function of collectoremitter voltage

## 9. Thermal characteristics

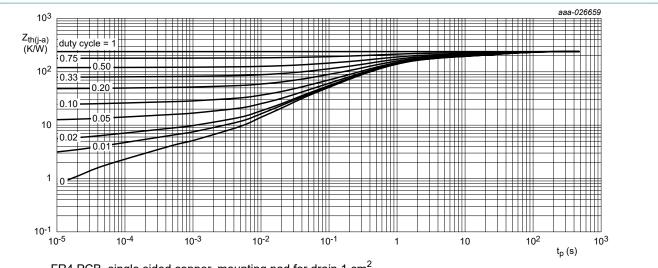
**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
			[2]	-	-	261	K/W
			[3]	-	-	250	K/W
			[4]	-	-	215	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	75	-	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

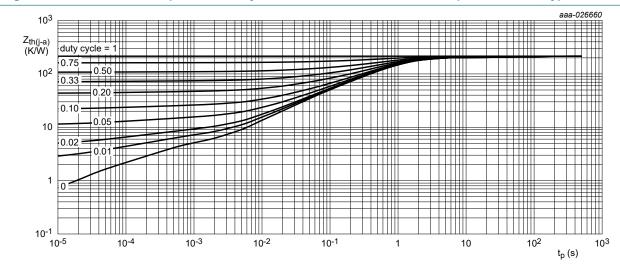


#### 50 V, 2 A PNP low VCEsat transistor



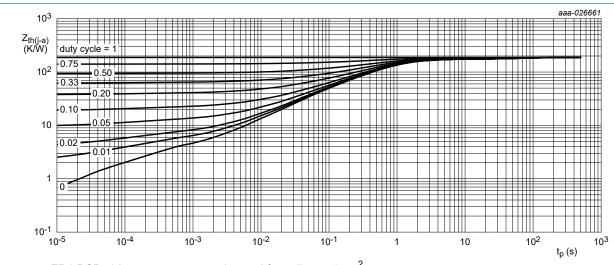
FR4 PCB, single sided copper, mounting pad for drain 1 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, mounting pad for collector 1 cm<sup>2</sup>

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 2 A PNP low VCEsat transistor

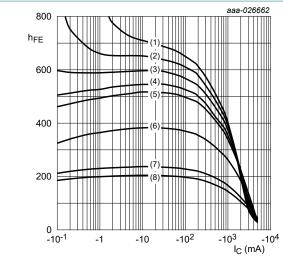
# 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C$ = -100 $\mu$ A; $I_E$ = 0 A; $T_{amb}$ = 25 °C		-50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = -10 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ mA}; I_E = -100 \mu\text{A}; T_{amb} = 25 \text{ °C}$		-7	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ °C}$		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -2 V; $I_{C}$ = -100 mA; $T_{amb}$ = 25 °C	[1]	200	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -500 mA; $T_{amb}$ = 25 °C	[1]	200	-	-	
		$V_{CE} = -2 \text{ V}; I_{C} = -1 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	200	-	-	
		$V_{CE} = -2 \text{ V}; I_{C} = -2 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	130	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -500 mA; $I_B$ = -50 mA; $T_{amb}$ = 25 °C	[1]	-	-	-90	mV
		$I_C = -1 \text{ A}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	-180	mV
		$I_C = -2 \text{ A}; I_B = -200 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	-	-	-300	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance		[1]	-	-	150	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -2 A; $I_B$ = -100 mA; $T_{amb}$ = 25 °C	[1]	-	-	-1.1	V
$V_{BE}$	base-emitter voltage	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -1 A	[1]	-	-	-1.2	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -100 mA; f = 100 MHz; $T_{amb}$ = 25 °C		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$		-	-	35	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

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 $V_{CE} = -2 V$ 

 $(1) T_{amb} = 175 °C$ 

 $(2) T_{amb} = 150 °C$ 

(3)  $T_{amb} = 125 \, ^{\circ}C$ 

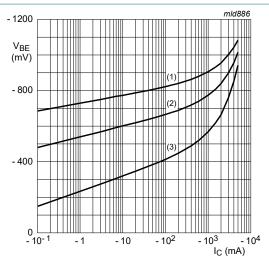
(4)  $T_{amb} = 100 \, ^{\circ}C$ 

(5) T<sub>amb</sub> = 85 °C

(6)  $T_{amb} = 25 \, ^{\circ}C$ 

 $(7) T_{amb} = -40 °C$ (8)  $T_{amb} = -55 \, ^{\circ}C$ 

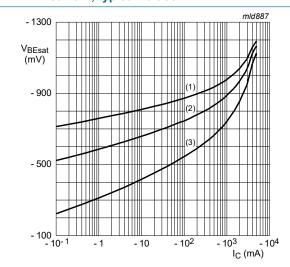
Fig. 7. DC current gain as a function of collector current; typical values



 $V_{CE} = -2 V$ (1)  $T_{amb} = -55 °C$ (2)  $T_{amb} = 25 °C$ 

 $(3) T_{amb} = 150 °C$ 

Fig. 8. Base-emitter voltage as a function of collector current; typical values

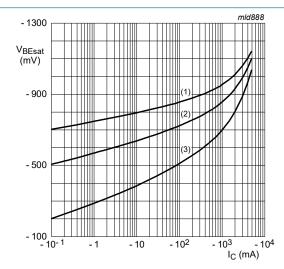


 $I_{\rm C}/I_{\rm B}=10$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 150 °C





 $I_{\rm C}/I_{\rm B}=20$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 150 °C

collector current; typical values

#### 50 V, 2 A PNP low VCEsat transistor

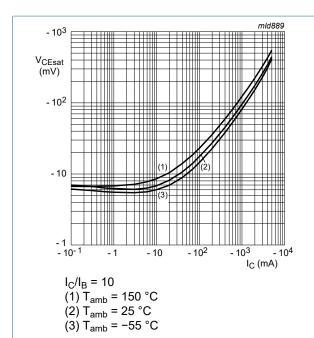


Fig. 11. Collector-emitter saturation voltage as a function of collector current; typical values

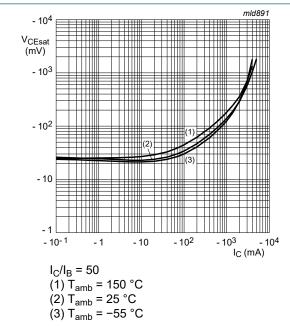
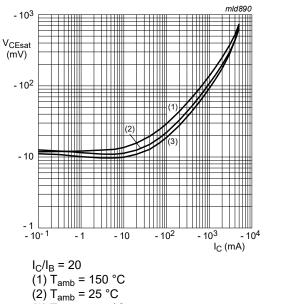
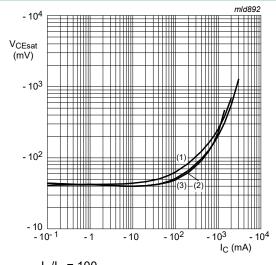


Fig. 13. Collector-emitter saturation voltage as a function of collector current; typical values



(1) T<sub>amb</sub> = 150 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

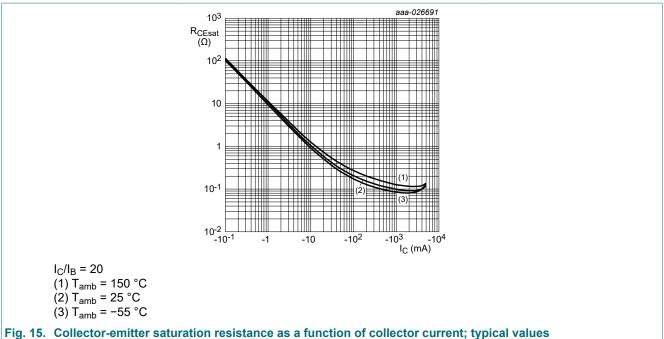
Fig. 12. Collector-emitter saturation voltage as a function of collector current; typical values



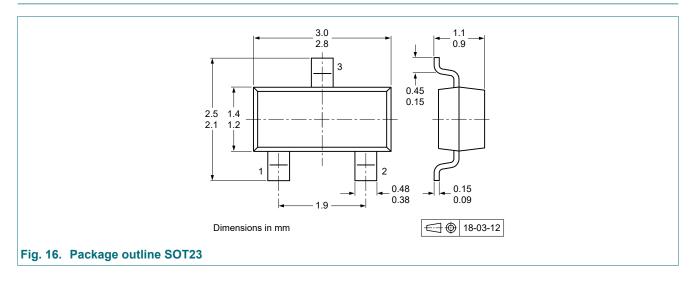
 $I_{\rm C}/I_{\rm B} = 100$ (1)  $T_{amb} = 150 \, ^{\circ}C$ (2)  $T_{amb} = 25 \, ^{\circ}C$ (3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values

#### 50 V, 2 A PNP low VCEsat transistor

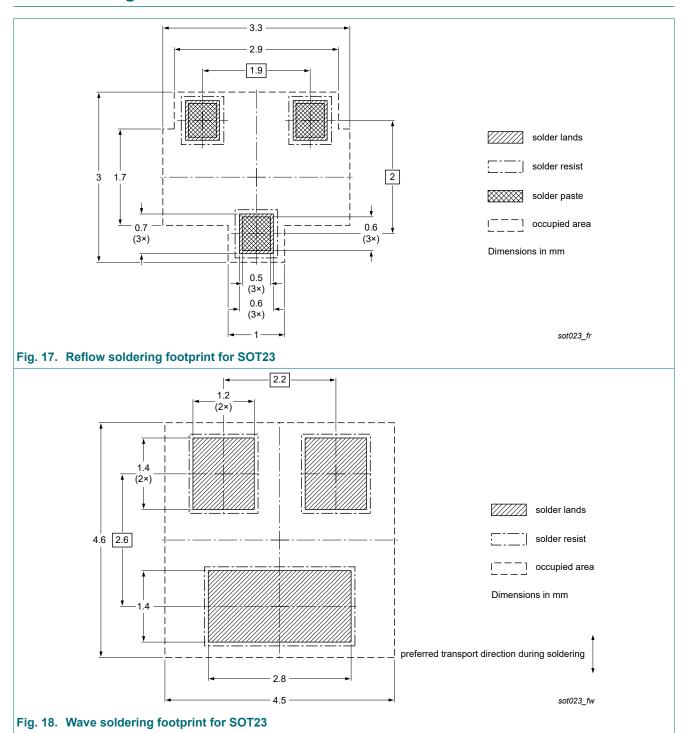


## 11. Package outline



#### 50 V, 2 A PNP low VCEsat transistor

# 12. Soldering



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# 13. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBSS5250TH v.3	20241008	Product data sheet	-	PBSS5250TH v.2				
Modifications:	Product changed to	Product changed to non automotive. Please refer to the automotive product(s) with -Q.						
PBSS5250TH v.2	20170809	Product data sheet	-	PBSS5250TH v.1				
PBSS5250TH v.1	20170421	Product data sheet	-	-				

### 50 V, 2 A PNP low VCEsat transistor

## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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